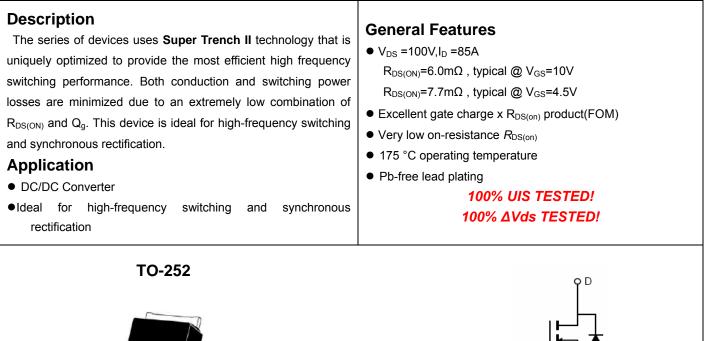
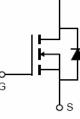




NCE N-Channel Super Trench II Power MOSFET







Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP065N10AK	NCEP065N10AK	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_c=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	100	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	Ι _D	85	А
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	65	A
Pulsed Drain Current	I _{DM}	340	A
Maximum Power Dissipation	PD	115	W
Derating factor		0.83	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	387	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 175	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	R _{θJC}	1.2	°C /W	
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Electrical Characteristics (T_c=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	100		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V	V _{DS} =100V,V _{GS} =0V		1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V -		-	±100	nA
On Characteristics (Note 3)			·	•		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.2	1.7	2.2	V
Drain Source On State Desistance	P	V_{GS} =10V, I _D =45A	-	6.0	6.5	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =45A	-	7.7	9.0	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =45A		60	-	S
Dynamic Characteristics (Note4)	· · · · ·					
Input Capacitance	C _{lss}		-	5580	-	PF
Output Capacitance	C _{oss}	V _{DS} =50V,V _{GS} =0V, F=1.0MHz	-	360	-	PF
Reverse Transfer Capacitance	C _{rss}		-	15	-	PF
Switching Characteristics (Note 4)			·	•		
Turn-on Delay Time	t _{d(on)}		-	17	-	nS
Turn-on Rise Time	tr	V _{DD} =50V,I _D =45A	-	10.5	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =1.6 Ω	-	40	-	nS
Turn-Off Fall Time	t _f			7	-	nS
Total Gate Charge	Qg		-	83	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =50V,I _D =45A,	-	13		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V		15		nC
Drain-Source Diode Characteristics			·	•		
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =45A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	85	Α
Reverse Recovery Time	t _{rr}	T_J = 25°C, I_F = 45A	-	68	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	110	-	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t \leq 10 sec.

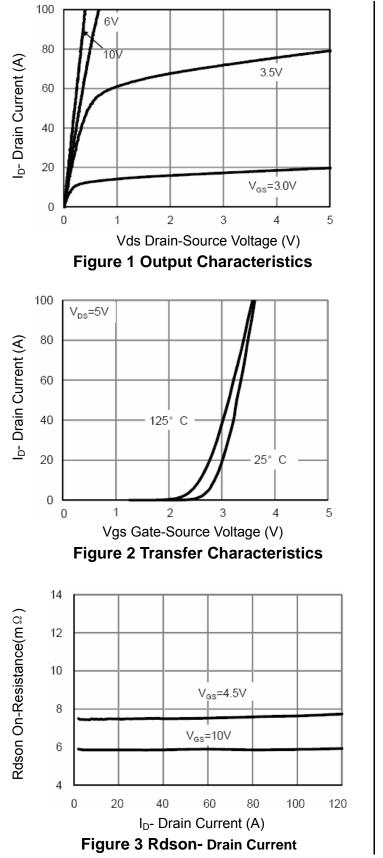
3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.

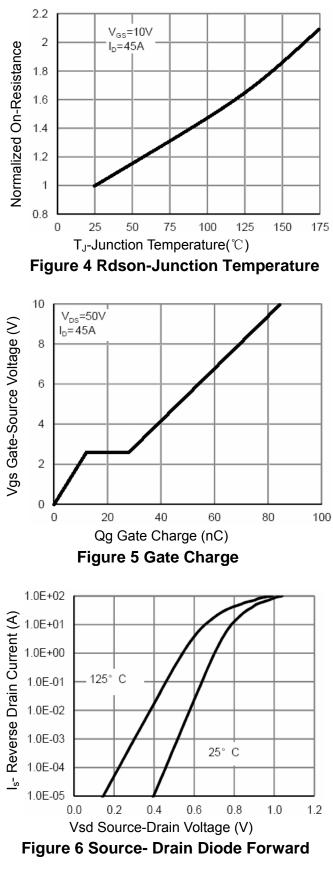
4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25 $^\circ \!\! \mathbb{C}$,V_{DD}=40V,V_G=10V,L=0.5mH,Rg=25 Ω











NCEP065N10AK

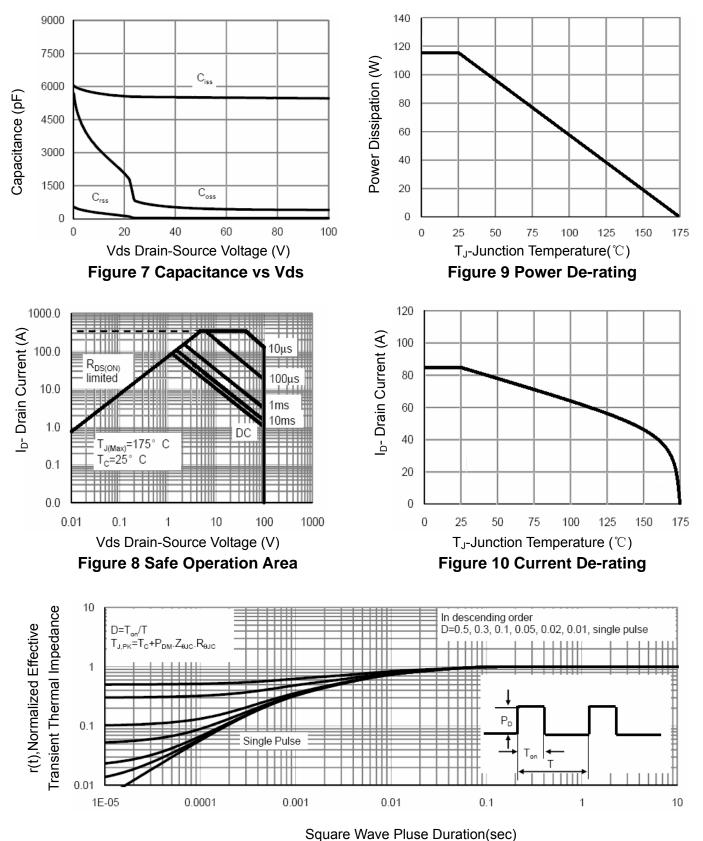
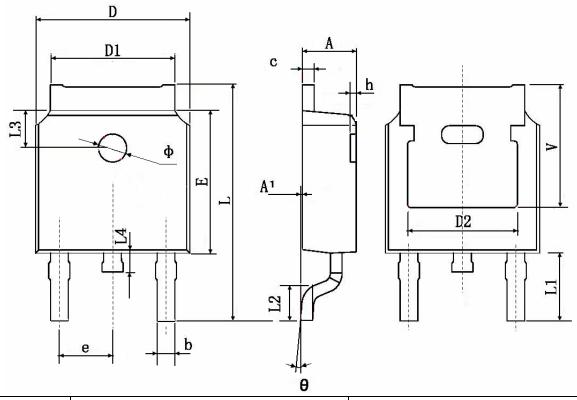


Figure 11 Normalized Maximum Transient Thermal Impedance



TO-252-2L Package Information



Symbol	Dimensions I	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.83	TYP.	0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	TYP.	0.211 TYP.		



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